

Vishay General Semiconductor

COMPLIANT

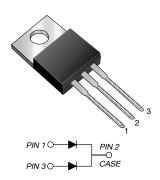
HALOGEN

FREE

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

TMBS[®]

TO-220AB



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5.0 A			
V_{RRM}	90 V, 100 V			
I _{FSM}	120 A			
V _F	0.75 V			
T _J max.	150 °C			
Package	TO-220AB			
Diode variation	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- · Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		MBR1090CT	MBR10100CT	UNIT	
Maximum repetitive peak reverse voltage		90	100	V	
Maximum peak reverse voltage		90	100	V	
Maximum DC blocking voltage		90	100	V	
Maximum average forward restified average at T 105 °C		10		Α	
Maximum average forward rectified current at T _C = 105 °C per d	iode I _{F(AV)}	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		120		А	
Voltage rate of change		10 000		V/µs	
Operating junction and storage temperature range		-65 to +150		°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1090CT	MBR10100CT	UNIT
Maximum instantaneous forward voltage	I _F = 5.0 A	T _A = 125 °C	V _F ⁽¹⁾	0.75		V
		T _A = 25 °C		0.	0.85	
Maximum reverse current per diode at working peak reverse voltage		T _A = 25 °C	I _R ⁽²⁾	100		μA
		T _A = 100 °C	'R (-)	6	.0	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

MBR1090CT, MBR10100CT

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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR1090CT MBR10100CT			
Typical thermal resistance per diode	$R_{ heta JC}$	4.4		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR10100CT-M3/4W	1.87	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

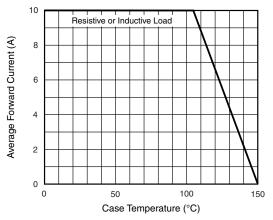


Fig. 1 - Forward Current Derating Curve

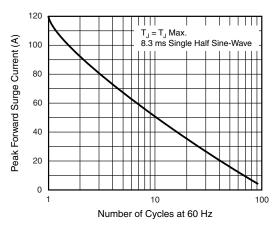


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

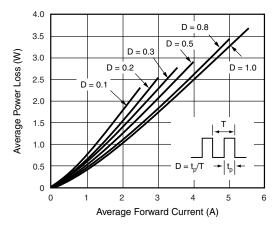


Fig. 3 - Forward Power Loss Characteristics Per Diode

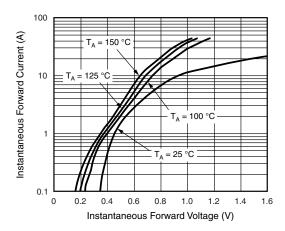


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

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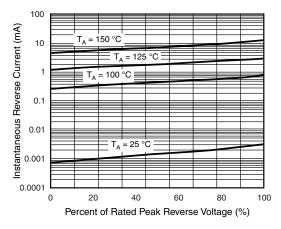


Fig. 5 - Typical Reverse Characteristics Per Diode

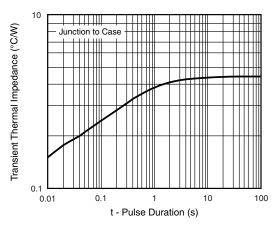


Fig. 7 - Typical Transient Thermal Impedance Per Diode

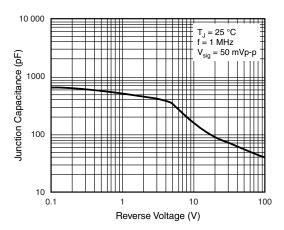
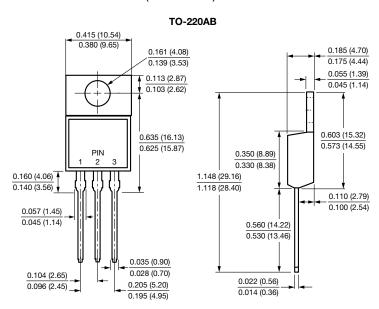


Fig. 6 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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